



## Vishay General Semiconductor

# **High-Voltage Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



| PRIMARY CHARACTERISTICS |             |  |  |  |
|-------------------------|-------------|--|--|--|
| I <sub>F(AV)</sub>      | 2.0 A       |  |  |  |
| $V_{RRM}$               | 90 V, 100 V |  |  |  |
| I <sub>FSM</sub>        | 75 A        |  |  |  |
| $V_{F}$                 | 0.65 V      |  |  |  |
| I <sub>R</sub>          | 10 μΑ       |  |  |  |
| T <sub>J</sub> max.     | 175 °C      |  |  |  |

### **FEATURES**

- Guardring for overvoltage protection
- · Low power losses and high efficiency
- · Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

## **TYPICAL APPLICATIONS**

For use in middle voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

### **MECHANICAL DATA**

Case: DO-204AC (DO-15)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix

meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                    |                    |                |     |      |  |
|--|--------------------|----------------|-----|------|--|
| PARAMETER  | SYMBOL             | SB2H90 SB2H100 |     | UNIT |  |
| Maximum repetitive peak reverse voltage  | $V_{RRM}$          | 90 100         |     | V    |  |
| Working peak reverse voltage   | $V_{RWM}$          | 90             | 100 | V    |  |
| Maximum DC blocking voltage  | $V_{DC}$           | 90             | 100 | V    |  |
| Maximum average forward rectified current at T <sub>A</sub> = 25 °C                | I <sub>F(AV)</sub> | 2.0            |     | А    |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I <sub>FSM</sub>   | 75             |     | А    |  |
| Peak repetitive reverse surge current at t <sub>p</sub> = 2.0 µs, 1 kHz            | I <sub>RRM</sub>   | 1.0            |     | А    |  |
| Critical rate of rise of reverse voltage   | dV/dt              | 10 000         |     | V/µs |  |
| Storage temperature range  | T <sub>STG</sub>   | - 55 to + 175  |     | °C   |  |
| Maximum operating junction temperature   | TJ                 | 17             | °C  |      |  |

# SB2H90, SB2H100

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |        |         |          |  |
|---|------------------------|-------------------------|-------------------------------|--------|---------|----------|--|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL                        | SB2H90 | SB2H100 | UNIT     |  |
| Maximum instantaneous forward voltage   | I <sub>F</sub> = 2.0 A | T <sub>J</sub> = 25 °C  | V <sub>E</sub> (1)            | 0.     | 79      | V        |  |
|   |                        | T <sub>J</sub> = 125 °C | <b>V</b> F (')                | 0.65   |         | <b>v</b> |  |
| Maximum reverse current at rated V <sub>B</sub>                                   |                        | T <sub>J</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 10     |         | μΑ       |  |
| Maximum reverse current at rated V <sub>R</sub>                                   |                        | T <sub>J</sub> = 125 °C |                               | 4.     | .0      | mA       |  |

#### Notes

 $^{(1)}$  Pulse test: 300 ms pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                      |        |         |      |  |
|---|----------------------|--------|---------|------|--|
| PARAMETER   | SYMBOL               | SB2H90 | SB2H100 | UNIT |  |
| Timing the word in a sistence   | R <sub>0JA</sub> (1) | 45     |         | °C/W |  |
| Typical thermal resistance  | R <sub>0JL</sub> (1) | 14     |         |      |  |

#### Note

 $^{(1)}$  P.C.B. mounted with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas

| ORDERING INFORMATION (Example) |                 |                        |               |                                  |  |
|--------------------------------|-----------------|------------------------|---------------|----------------------------------|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                    |  |
| SB2H100-E3/54                  | 0.398           | 54                     | 4000          | 13" diameter paper tape and reel |  |
| SB2H100-E3/73                  | 0.398           | 73                     | 2000          | Ammo pack packaging              |  |
| SB2H100HE3/54 <sup>(1)</sup>   | 0.398           | 54                     | 4000          | 13" diameter paper tape and reel |  |
| SB2H100HE3/73 <sup>(1)</sup>   | 0.398           | 73                     | 2000          | Ammo pack packaging              |  |

#### Note

(1) AEC-Q101 qualified

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

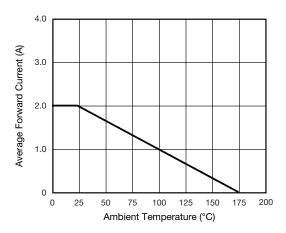


Fig. 1 - Forward Current Derating Curve

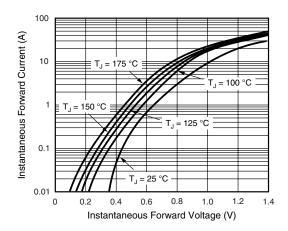
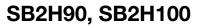


Fig. 2 - Typical Instantaneous Forward Characteristics





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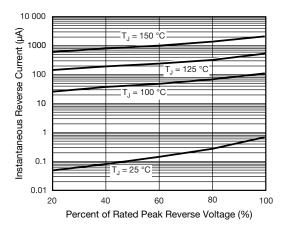


Fig. 3 - Typical Reverse Characteristics

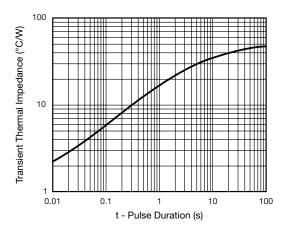


Fig. 5 - Typical Transient Thermal Impedance

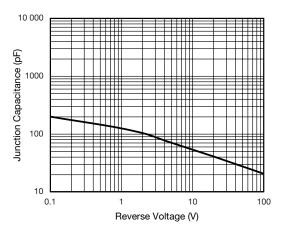
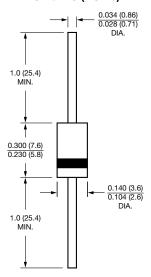


Fig. 4 - Typical Junction Capacitance

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

## DO-204AC (DO-15)





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